NSN 5961-00-122-1189

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-122-1189 **Inclosure Material:** Metal **Overall Length:** 0.220 inches **Terminal Length:** 0.360 inches **Overall Diameter:** 0.420 inches **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 breakover voltage, dc **Current Rating Per Characteristic:** 5.00 amperes collector current, dc **Power Rating Per Characteristic:** 500.0 milliwatts peak gate power dissipation **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 2 tab, solder lug and 1 case **Specification Data:** 80131-release5221 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0